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Details

Product Status	Active
Core Processor	HCS12X
Core Size	16-Bit
Speed	80MHz
Connectivity	CANbus, EBI/EMI, I ² C, IrDA, LINbus, SCI, SPI
Peripherals	LVD, POR, PWM, WDT
Number of I/O	91
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	2.35V ~ 5.5V
Data Converters	A/D 16x10b
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	112-LQFP
Supplier Device Package	112-LQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mc9s12xdp512cal

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pull-down device which is only active when $\overline{\text{RESET}}$ is low. $\overline{\text{TAGHI}}$ is used to tag the high half of the instruction word being read into the instruction queue.

The input voltage threshold for PE6 can be configured to reduced levels, to allow data from an external 3.3-V peripheral to be read by the MCU operating at 5.0 V. The input voltage threshold for PE6 is configured to reduced levels out of reset in expanded and emulation modes.

1.2.3.18 PE5 / MODA / TAGLO / RE — Port E I/O Pin 5

PE5 is a general-purpose input or output pin. It is used as a MCU operating mode select pin during reset. The state of this pin is latched to the MODA bit at the rising edge of $\overline{\text{RESET}}$. This pin is shared with the read enable $\overline{\text{RE}}$ output. This pin is an input with a pull-down device which is only active when $\overline{\text{RESET}}$ is low. $\overline{\text{TAGLO}}$ is used to tag the low half of the instruction word being read into the instruction queue.

The input voltage threshold for PE5 can be configured to reduced levels, to allow data from an external 3.3-V peripheral to be read by the MCU operating at 5.0 V. The input voltage threshold for PE5 is configured to reduced levels out of reset in expanded and emulation modes.

1.2.3.19 PE4 / ECLK — Port E I/O Pin 4

PE4 is a general-purpose input or output pin. It can be configured to drive the internal bus clock ECLK. ECLK can be used as a timing reference.

1.2.3.20 PE3 / LSTRB / LDS / EROMCTL— Port E I/O Pin 3

PE3 is a general-purpose input or output pin. In MCU expanded modes of operation, $\overline{\text{LSTRB}}$ or $\overline{\text{LDS}}$ can be used for the low byte strobe function to indicate the type of bus access. At the rising edge of $\overline{\text{RESET}}$ the state of this pin is latched to the EROMON bit.

1.2.3.21 PE2 / R/W / WE—Port E I/O Pin 2

PE2 is a general-purpose input or output pin. In MCU expanded modes of operations, this pin drives the read/write output signal or write enable output signal for the external bus. It indicates the direction of data on the external bus

1.2.3.22 PE[6:2] — Port E I/O Pins

PE[6:2] are general-purpose input or output pins.

1.2.3.23 PE1 / IRQ — Port E Input Pin 1

PE1 is a general-purpose input pin and the maskable interrupt request input that provides a means of applying asynchronous interrupt requests. This will wake up the MCU from stop or wait mode.

1.2.3.24 PE0 / XIRQ — Port E Input Pin 0

PE0 is a general-purpose input pin and the non-maskable interrupt request input that provides a means of applying asynchronous interrupt requests. This will wake up the MCU from stop or wait mode.



		Pin Number		Nominal		
Mnemonic	144-Pin LQFP	112-Pin LQFP	80-Pin QFP	Voltage	Description	
V _{DD1, 2}	15, 87	13, 65	9, 49	2.5 V	Internal power and ground generated by	
V _{SS1, 2}	16, 88	14, 66	10, 50	0V	Internal regulator	
V _{DDR1}	53	41	29	5.0 V	External power and ground, supply to pin	
V _{SSR1}	52	40	28	0 V	drivers and internal voltage regulator	
V _{DDX1}	139	107	77	5.0 V	External power and ground, supply to pin	
V _{SSX1}	138	106	76	0 V	drivers	
V _{DDX2}	26	N.A.	N.A.	5.0 V	External power and ground, supply to pin	
V _{SSX2}	27	N.A.	N.A.	0 V	drivers	
V _{DDR2}	82	N.A.	N.A.	5.0 V	External power and ground, supply to pin	
V _{SSR2}	81	N.A.	N.A.	0 V	drivers	
V _{DDA}	107	83	59	5.0 V	Operating voltage and ground for the	
V _{SSA}	110	86	62	0 V	analog-to-digital converters and the reference for the internal voltage regulator, allows the supply voltage to the A/D to be bypassed independently.	
V _{RL}	109	85	61	0 V	Reference voltages for the analog-to-digital	
V _{RH}	108	84	60	5.0 V	converter.	
V _{DDPLL}	55	43	31	2.5 V	Provides operating voltage and ground for	
V _{SSPLL}	57	45	33	0 V	the phased-locked loop. This allows the supply voltage to the PLL to be bypassed independently. Internal power and ground generated by internal regulator.	

Table 1-8. MC9S12XD Family Power and Ground Connection Summary



BPL

Branch if Plus



Operation

If N = 0, then PC + $0002 + (REL9 \le 1) \Rightarrow PC$

Tests the Sign flag and branches if N = 0.

CCR Effects

Ν	Ζ	V	С



- N: Not affected.
- Z: Not affected.
- V: Not affected.
- C: Not affected.

Code and CPU Cycles

Source Form	Address Mode	Machine Code		Cycles						
BPL REL9	REL9	0	0	1	0	1	0	0	REL9	PP/P



Chapter 10 Freescale's Scalable Controller Area Network (S12MSCANV3)



Figure 10-16. MSCAN Reserved Register

Read: Always read 0x0000 in normal system operation modes Write: Unimplemented in normal system operation modes

NOTE

Writing to this register when in special modes can alter the MSCAN functionality.

10.3.2.14 MSCAN Miscellaneous Register (CANMISC)

This register provides additional features.



Read: Anytime

Write: Anytime; write of '1' clears flag; write of '0' ignored

Table 10-19. CANMISC Register Field Descriptions

Field	Description
0	Bus-off State Hold Until User Request — If BORM is set in Section 10.3.2.2, "MSCAN Control Register 1
BOHOLD	(CANCTL1), this bit indicates whether the module has entered the bus-off state. Clearing this bit requests the
	recovery from bus-off. Refer to Section 10.5.2, "Bus-Off Recovery," for details.
	0 Module is not bus-off or recovery has been requested by user in bus-off state
	1 Module is bus-off and holds this state until user request

10.3.2.15 MSCAN Receive Error Counter (CANRXERR)

This register reflects the status of the MSCAN receive error counter.

Syntax	Description
SYNC_SEG	System expects transitions to occur on the CAN bus during this period.
Transmit Point	A node in transmit mode transfers a new value to the CAN bus at this point.
Sample Point	A node in receive mode samples the CAN bus at this point. If the three samples per bit option is selected, then this point marks the position of the third sample.

The synchronization jump width (see the Bosch CAN specification for details) can be programmed in a range of 1 to 4 time quanta by setting the SJW parameter.

The SYNC_SEG, TSEG1, TSEG2, and SJW parameters are set by programming the MSCAN bus timing registers (CANBTR0, CANBTR1) (see Section 10.3.2.3, "MSCAN Bus Timing Register 0 (CANBTR0)" and Section 10.3.2.4, "MSCAN Bus Timing Register 1 (CANBTR1)").

Table 10-35 gives an overview of the CAN compliant segment settings and the related parameter values.

NOTE

It is the user's responsibility to ensure the bit time settings are in compliance with the CAN standard.

Time Segment 1	TSEG1	Time Segment 2	TSEG2	Synchronization Jump Width	SJW
5 10	49	2	1	12	01
4 11	3 10	3	2	13	02
5 12	4 11	4	3	14	03
6 13	5 12	5	4	14	03
714	6 13	6	5	14	03
8 15	7 14	7	6	14	03
9 16	8 15	8	7	14	03

Table 10-35. CAN Standard Compliant Bit Time Segment Settings

10.4.4 Modes of Operation

10.4.4.1 Normal Modes

The MSCAN module behaves as described within this specification in all normal system operation modes.

10.4.4.2 Special Modes

The MSCAN module behaves as described within this specification in all special system operation modes.



12.3.2.1 SPI Control Register 1 (SPICR1)



Figure 12-3. SPI Control Register 1 (SPICR1)

Read: Anytime

Write: Anytime

Table	12-1.	SPICR1	Field	Descri	ptions	

Field	Description
7 SPIE	 SPI Interrupt Enable Bit — This bit enables SPI interrupt requests, if SPIF or MODF status flag is set. SPI interrupts disabled. SPI interrupts enabled.
6 SPE	 SPI System Enable Bit — This bit enables the SPI system and dedicates the SPI port pins to SPI system functions. If SPE is cleared, SPI is disabled and forced into idle state, status bits in SPISR register are reset. SPI disabled (lower power consumption). SPI enabled, port pins are dedicated to SPI functions.
5 SPTIE	 SPI Transmit Interrupt Enable — This bit enables SPI interrupt requests, if SPTEF flag is set. 0 SPTEF interrupt disabled. 1 SPTEF interrupt enabled.
4 MSTR	 SPI Master/Slave Mode Select Bit — This bit selects whether the SPI operates in master or slave mode. Switching the SPI from master to slave or vice versa forces the SPI system into idle state. SPI is in slave mode. SPI is in master mode.
3 CPOL	 SPI Clock Polarity Bit — This bit selects an inverted or non-inverted SPI clock. To transmit data between SPI modules, the SPI modules must have identical CPOL values. In master mode, a change of this bit will abort a transmission in progress and force the SPI system into idle state. 0 Active-high clocks selected. In idle state SCK is low. 1 Active-low clocks selected. In idle state SCK is high.
2 CPHA	 SPI Clock Phase Bit — This bit is used to select the SPI clock format. In master mode, a change of this bit will abort a transmission in progress and force the SPI system into idle state. 0 Sampling of data occurs at odd edges (1,3,5,,15) of the SCK clock. 1 Sampling of data occurs at even edges (2,4,6,,16) of the SCK clock.
1 SSOE	Slave Select Output Enable — The \overline{SS} output feature is enabled only in master mode, if MODFEN is set, by asserting the SSOE as shown in Table 12-2. In master mode, a change of this bit will abort a transmission in progress and force the SPI system into idle state.
0 LSBFE	 LSB-First Enable — This bit does not affect the position of the MSB and LSB in the data register. Reads and writes of the data register always have the MSB in bit 7. In master mode, a change of this bit will abort a transmission in progress and force the SPI system into idle state. 0 Data is transferred most significant bit first. 1 Data is transferred least significant bit first.

¹⁷ 17 Memory Mapping Control (S12XMMCV2)

17.5.3 On-Chip ROM Control

The MCU offers two modes to support emulation. In the first mode (called generator) the emulator provides the data instead of the internal FLASH and traces the CPU actions. In the other mode (called observer) the internal FLASH provides the data and all internal actions are made visible to the emulator.

17.5.3.1 ROM Control in Single-Chip Modes

In single-chip modes the MCU has no external bus. All memory accesses and program fetches are internal (see Figure 1-27).



Figure 17-27. ROM in Single Chip Modes

17.5.3.2 ROM Control in Emulation Single-Chip Mode

In emulation single-chip mode the external bus is connected to the emulator. If the EROMON bit is set, the internal FLASH provides the data and the emulator can observe all internal CPU actions on the external bus. If the EROMON bit is cleared, the emulator provides the data (generator) and traces the all CPU actions (see Figure 1-28).



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I



18.4.4 Chip Bus Control

The MMC controls the address buses and the data buses that interface the S12X masters (CPU, BDMand XGATE) with the rest of the system (master buses). In addition the MMC handles all CPU read data bus swapping operations. All internal and external resources are connected to specific target buses (see Figure 18-26¹).



Figure 18-26. MMC Block Diagram

^{1.} Doted blocks and lines are optional. Please refer to the Device User Guide for their availlibilities.

18 Memory Mapping Control (S12XMMCV3)

18.5.3 On-Chip ROM Control

The MCU offers two modes to support emulation. In the first mode (called generator) the emulator provides the data instead of the internal FLASH and traces the CPU actions. In the other mode (called observer) the internal FLASH provides the data and all internal actions are made visible to the emulator.

18.5.3.1 ROM Control in Single-Chip Modes

In single-chip modes the MCU has no external bus. All memory accesses and program fetches are internal (see Figure 18-27).



Figure 18-27. ROM in Single Chip Modes

18.5.3.2 ROM Control in Emulation Single-Chip Mode

In emulation single-chip mode the external bus is connected to the emulator. If the EROMON bit is set, the internal FLASH provides the data and the emulator can observe all internal CPU actions on the external bus. If the EROMON bit is cleared, the emulator provides the data (generator) and traces the all CPU actions (see Figure 18-28).



Figure 18-28. ROM in Emulation Single-Chip Mode

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Field	Description
1 XRW	 Read Write Indicator — This bit indicates if the corresponding stored address corresponds to a read or write access. This bit only contains valid information when tracing XGATE activity in detail mode. 0 Read/Write Access 1 Access
0 XOCF	 XGATE Opcode Fetch Indicator — This bit indicates if the stored address corresponds to an opcode fetch cycle. This bit only contains valid information when tracing the CPU accesses in detail mode. 0 Stored information does not correspond to opcode fetch cycle 1 Stored information corresponds to opcode fetch cycle

19.4.5.3.2 Reading Data from Trace Buffer

The data stored in the trace buffer can be read using either the background debug module (BDM) module or the CPU provided the DBG module is not armed, is configured for tracing (at least one TSOURCE bit is set) and the system not secured. When the ARM bit is written to 1 the trace buffer is locked to prevent reading. The trace buffer can only be unlocked for reading by a single aligned word write to DBGTB when the module is disarmed. Multiple writes to the DBGTB are not allowed since they increment the pointer.

The trace buffer can only be read through the DBGTB register using aligned word reads, any byte or misaligned reads return 0 and do not cause the trace buffer pointer to increment to the next trace buffer address. The trace buffer data is read out first-in first-out. By reading CNT in DBGCNT the number of valid 64-bit lines can be determined. DBGCNT will not decrement as data is read.

Whilst reading an internal pointer is used to determine the next line to be read. After a tracing session, the pointer points to the oldest data entry, thus if no overflow has occurred, the pointer points to line0, otherwise it points to the line with the oldest entry. The pointer is initialized by each aligned write to DBGTBH to point to the oldest data again. This enables an interrupted trace buffer read sequence to be easily restarted from the oldest data entry.

The least significant word of each 64-bit wide array line is read out first. This corresponds to the bytes 1 and 0 of Table 19-39. The bytes containing invalid information (shaded in Table 19-39) are also read out.

Reading the trace buffer while the DBG module is armed will return invalid data and no shifting of the RAM pointer will occur. Reading the trace buffer is not possible if both TSOURCE bits are cleared.



22.3.2.55 Port J Input Register (PTIJ)



¹ These registers are reset to zero. Two bus clock cycles after reset release the register values are updated with the associated pin values.

Read: Anytime.

Write: Never, writes to this register have no effect.

This register always reads back the buffered state of the associated pins. This can be used to detect overload or short circuit conditions on output pins.

27 512 Kbyte Flash Module (S12XFTX512K4V2)

Register Name		Bit 7	6	5	4	3	2	1	Bit 0
RESERVED2	R	0	0	0	0	0	0	0	0
	w								
RESERVED3	R	0	0	0	0	0	0	0	0
REGERVEDS		0	0	0	0	v	U	U	0
	vv								
RESERVED4	R	0	0	0	0	0	0	0	0
	w								



27.3.2.1 Flash Clock Divider Register (FCLKDIV)

The FCLKDIV register is used to control timed events in program and erase algorithms.



Figure 27-4. Flash Clock Divider Register (FCLKDIV)

All bits in the FCLKDIV register are readable, bits 6-0 are write once and bit 7 is not writable.

Table 27-3. FCLKDIV Field Descriptions

Field	Description
7 FDIVLD	 Clock Divider Loaded. 0 Register has not been written. 1 Register has been written to since the last reset.
6 PRDIV8	 Enable Prescalar by 8. 0 The oscillator clock is directly fed into the clock divider. 1 The oscillator clock is divided by 8 before feeding into the clock divider.
5-0 FDIV[5:0]	Clock Divider Bits — The combination of PRDIV8 and FDIV[5:0] must divide the oscillator clock down to a frequency of 150 kHz–200 kHz. The maximum divide ratio is 512. Please refer to Section 27.4.1.1, "Writing the FCLKDIV Register" for more information.

27.3.2.2 Flash Security Register (FSEC)

The FSEC register holds all bits associated with the security of the MCU and Flash module.



- Security feature to prevent unauthorized access to the Flash memory
- Code integrity check using built-in data compression

28.1.3 Modes of Operation

Program, erase, erase verify, and data compress operations (please refer to Section 28.4.1, "Flash Command Operations" for details).

28.1.4 Block Diagram

A block diagram of the Flash module is shown in Figure 28-1.



Figure 28-1. FTX256K2 Block Diagram

28.2 External Signal Description

The Flash module contains no signals that connect off-chip.





CBEIE, CCIE and KEYACC bits are readable and writable while all remaining bits read 0 and are not writable in normal mode. KEYACC is only writable if KEYEN (see Section 28.3.2.2, "Flash Security Register (FSEC)" is set to the enabled state. BKSEL is readable and writable in special mode to simplify mass erase and erase verify operations. When writing to the FCNFG register in special mode, all unimplemented/ reserved bits must be written to 0.

-
Description
nand Buffer Empty Interrupt Enable — The CBEIE bit enables an interrupt in case o

Table 28-8. FCNFG Field Descriptions

7 CBEIE	 Command Buffer Empty Interrupt Enable — The CBEIE bit enables an interrupt in case of an empty command buffer in the Flash module. 0 Command buffer empty interrupt disabled. 1 An interrupt will be requested whenever the CBEIF flag (see Section 28.3.2.6, "Flash Status Register (FSTAT)") is set.
6 CCIE	 Command Complete Interrupt Enable — The CCIE bit enables an interrupt in case all commands have been completed in the Flash module. 0 Command complete interrupt disabled. 1 An interrupt will be requested whenever the CCIF flag (see Section 28.3.2.6, "Flash Status Register (FSTAT)") is set.
5 KEYACC	 Enable Security Key Writing Flash writes are interpreted as the start of a command write sequence. Writes to Flash array are interpreted as keys to open the backdoor. Reads of the Flash array return invalid data.
0 BKSEL	 Block Select — The BKSEL bit indicates which register bank is active. 0 Select register bank associated with Flash block 0. 1 Select register bank associated with Flash block 1.

28.3.2.5 Flash Protection Register (FPROT)

The FPROT register defines which Flash sectors are protected against program or erase operations.

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Field

28 256 Kbyte Flash Module (S12XFTX256K2V1)



Figure 28-26. Example Data Compress Command Flow

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28 256 Kbyte Flash Module (S12XFTX256K2V1)

- 10. If Flash block 5 is selected for compression, DATA equal to the contents of the MISR for Flash block 5 is compressed into the MISR for Flash block 0.
- 11. If Flash block 6 is selected for compression, DATA equal to the contents of the MISR for Flash block 6 is compressed into the MISR for Flash block 0.
- 12. If Flash block 7 is selected for compression, DATA equal to the contents of the MISR for Flash block 7 is compressed into the MISR for Flash block 0.
- 13. The contents of the MISR for Flash block 0 are written to the FDATA registers.





Figure 29-2. Flash Memory Map

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29.4.2.2 Data Compress Command

The data compress operation will check Flash code integrity by compressing data from a selected portion of the Flash memory into a signature analyzer.

An example flow to execute the data compress operation is shown in Figure 29-24. The data compress command write sequence is as follows:

- 1. Write to a Flash block address to start the command write sequence for the data compress command. The address written determines the starting address for the data compress operation and the data written determines the number of consecutive words to compress. If the data value written is 0x0000, 64K addresses or 128 Kbytes will be compressed.
- 2. Write the data compress command, 0x06, to the FCMD register.
- 3. Clear the CBEIF flag in the FSTAT register by writing a 1 to CBEIF to launch the data compress command.

After launching the data compress command, the CCIF flag in the FSTAT register will set after the data compress operation has completed. The number of bus cycles required to execute the data compress operation is equal to two times the number of consecutive words to compress plus 18 bus cycles as measured from the time the CBEIF flag is cleared until the CCIF flag is set. Once the CCIF flag is set, the signature generated by the data compress operation is available in the FDATA registers. The signature in the FDATA registers can be compared to the expected signature to determine the integrity of the selected data stored in the selected Flash memory. If the last address of a Flash block is reached during the data compress operation, data compression will continue with the starting address of the Flash block. The MRDS bits in the FTSTMOD register will determine the sense-amp margin setting during the data compress operation.

NOTE

Since the FDATA registers (or data buffer) are written to as part of the data compress operation, a command write sequence is not allowed to be buffered behind a data compress command write sequence. The CBEIF flag will not set after launching the data compress command to indicate that a command should not be buffered behind it. If an attempt is made to start a new command write sequence with a data compress operation active, the ACCERR flag in the FSTAT register will be set. A new command write sequence should only be started after reading the signature stored in the FDATA registers.

In order to take corrective action, it is recommended that the data compress command be executed on a Flash sector or subset of a Flash sector. If the data compress operation on a Flash sector returns an invalid signature, the Flash sector should be erased using the sector erase command and then reprogrammed using the program command.

The data compress command can be used to verify that a sector or sequential set of sectors are erased.



A.1.9 I/O Characteristics

This section describes the characteristics of all I/O pins except EXTAL, XTAL, XFC, TEST, VREGEN and supply pins.

CAUTION

The internal pull up/pull down device specification is different depending on maskset.

Condit I/O Ch	ion: ara	s are 3.15 V < V _{DD35} < 3.6 V temperature from –40°C t cteristics for all I/O pins except EXTAL, XTAL,XFC,TES	to +140°C, u ST, VREGEN	inless otherwis I and supply p	se noted ins.		
Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	Ρ	Input high voltage	V _{IH}	0.65*V _{DD35}	_	—	V
	Т	Input high voltage	V _{IH}	—	—	V _{DD35} + 0.3	V
2	Ρ	Input low voltage	V _{IL}	—	—	0.35*V _{DD35}	V
	Т	Input low voltage	V _{IL}	$V_{SS35} - 0.3$	—	—	V
3	С	Input hysteresis	V _{HYS}		250		mV
4	С	Input leakage current (pins in high impedance input mode) ¹ Vin = V _{DD35} or V _{SS35}	l _. in	-1	—	1	μA
5	С	Output high voltage (pins in output mode) Partial drive $I_{OH} = -0.75$ mA	V _{OH}	V _{DD35} – 0.4	—	—	V
6	Р	Output high voltage (pins in output mode) Full drive I _{OH} = -4 mA	V _{OH}	V _{DD35} – 0.4	—	—	V
7	С	Output low voltage (pins in output mode) Partial Drive I _{OL} = +0.9 mA	V _{OL}	—	—	0.4	V
8	Ρ	Output low voltage (pins in output mode) Full Drive I _{OL} = +4.75 mA	V _{OL}	—	—	0.4	V
	Ir	ternal pull up/pull down device specification (item	is 9 to 12) o	nly valid for n	nasksets 0L	15Y & 1L15Y	
9	Ρ	Internal pull up device current, tested at V_{IL} max.	I _{PUL}	—	_	-60	μA
10	С	Internal pull up device current, tested at V_{IH} min.	I _{PUH}	-6	_	-	μA
11	Ρ	Internal pull down device current, tested at $\mathrm{V}_{\mathrm{IH}}\mathrm{min}.$	I _{PDH}	—		60	μA
12	С	C Internal pull down device current, tested at V _{IL} max. I _{PDL} 6 — —					
		Internal pull up/pull down device specification	(items 13 to	o 14) valid for	all other ma	asksets	
13	Ρ	Internal pull up resistance VIH min > input voltage > VIL max	R _{PUL}	25		55	KΩ
14	Ρ	Internal pull down resistance VIH min > input voltage > VIL max	R _{PDH}	25		55	KΩ
15	D	Input capacitance	C _{in}	—	6	—	pF
16	Т	Injection current ² Single pin limit Total device limit, sum of all injected currents	I _{ICS} I _{ICP}	2.5 25	_	2.5 25	mA

Table A-6. 3.3-V I/O Characteristics

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ix G Detailed Register Map

0x0040–0x007F Enhanced Capture Timer 16-Bit 8-Channels (ECT) Map (Sheet 1 of 3)

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0x0040	TIOS	R W	IOS7	IOS6	IOS5	IOS4	IOS3	IOS2	IOS1	IOS0
0x0041	CFORC	R	0	0	0	0	0	0	0	0
0.00011	0.0110	W	FOC7	FOC6	FOC5	FOC4	FOC3	FOC2	FOC1	FOC0
0x0042	OC7M	R W	OC7M7	OC7M6	OC7M5	OC7M4	OC7M3	OC7M2	OC7M1	OC7M0
0x0043	OC7D	R W	OC7D7	OC7D6	OC7D5	OC7D4	OC7D3	OC7D2	OC7D1	OC7D0
0x0044	TCNT (hi)	R W	Bit 15	14	13	12	11	10	9	Bit 8
0x0045	TCNT (lo)	R W	Bit 7	6	5	4	3	2	1	Bit 0
0x0046	TSCR1	R W	TEN	TSWAI	TSFRZ	TFFCA	PRNT	0	0	0
0x0047	TTOV	R W	TOV7	TOV6	TOV5	TOV4	TOV3	TOV2	TOV1	TOV0
0x0048	TCTL1	R W	OM7	OL7	OM6	OL6	OM5	OL5	OM4	OL4
0x0049	TCTL2	R W	OM3	OL3	OM2	OL2	OM1	OL1	OM0	OL0
0x004A	TCTL3	R W	EDG7B	EDG7A	EDG6B	EDG6A	EDG5B	EDG5A	EDG4B	EDG4A
0x004B	TCTL4	R W	EDG3B	EDG3A	EDG2B	EDG2A	EDG1B	EDG1A	EDG0B	EDG0A
0x004C	TIE	R W	C7I	C6I	C5I	C4I	C3I	C2I	C1I	C0I
0x004D	TSCR2	R W	ΤΟΙ	0	0	0	TCRE	PR2	PR1	PR0
0x004E	TFLG1	R W	C7F	C6F	C5F	C4F	C3F	C2F	C1F	C0F
0x004F	TFLG2	R	TOF	0	0	0	0	0	0	0
0x0050	TC0 (hi)	R W	Bit 15	14	13	12	11	10	9	Bit 8
0x0051	TC0 (lo)	R W	Bit 7	6	5	4	3	2	1	Bit 0
0x0052	TC1 (hi)	R W	Bit 15	14	13	12	11	10	9	Bit 8
0x0053	TC1 (lo)	R W	Bit 7	6	5	4	3	2	1	Bit 0
0x0054	TC2 (hi)	R W	Bit 15	14	13	12	11	10	9	Bit 8
0x0055	TC2 (lo)	R W	Bit 7	6	5	4	3	2	1	Bit 0